

Silicon NPN Power Transistors

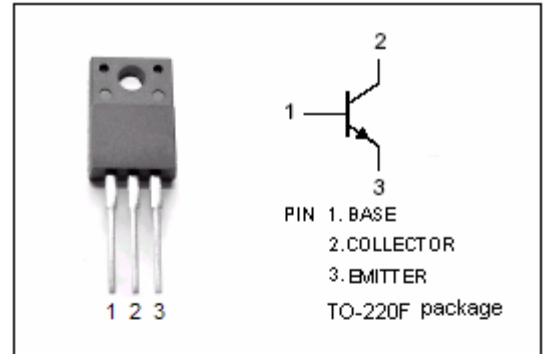
BU406FI/407FI

DESCRIPTION

- High Voltage
- Fast Switching Speed-
: $t_{off} = 0.75 \mu s$ (Max)
- Low Saturation Voltage-
: $V_{CE(sat)} = 1.0V$ (Max)@ $I_C = 5A$

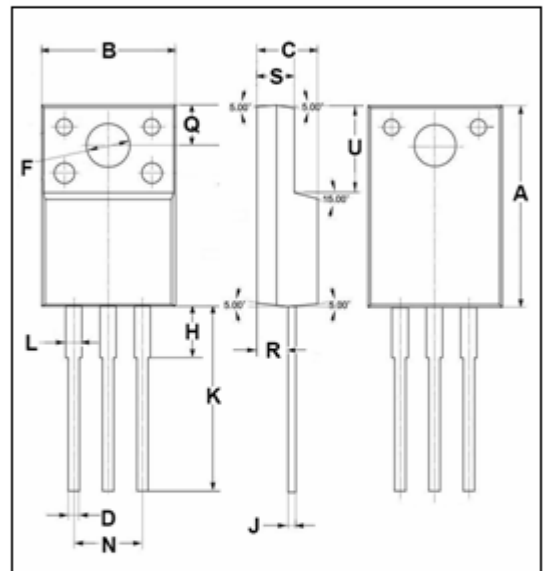
APPLICATIONS

- Designed for use in converters, inverters, switching regulators and motor control systems etc.



ABSOLUTE MAXIMUM RATINGS($T_a=25$)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CES}	Collector-Emitter Voltage	BU406FI	400	V
		BU407FI	330	
V_{CEO}	Collector-Emitter Voltage	BU406FI	200	V
		BU407FI	150	
V_{EBO}	Emitter-Base Voltage	5	V	
I_C	Collector Current-Continuous	7	A	
I_{CM}	Collector Current-Peak	15	A	
I_B	Base Current-Continuous	4	A	
I_{BM}	Base Current-Peak	6	A	
P_C	Collector Power Dissipation @ $T_C=25$	18	W	
T_J	Junction Temperature	150		
T_{stg}	Storage Temperature Range	-65~150		



DIM	mm	
	MIN	MAX
A	14.95	15.05
B	10.00	10.10
C	4.40	4.60
D	0.75	0.80
F	3.10	3.30
H	3.70	3.90
J	0.50	0.70
K	13.4	13.6
L	1.10	1.30
N	5.00	5.20
Q	2.70	2.90
R	2.20	2.40
S	2.65	2.85
U	6.40	6.60

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	7	/W
$R_{th j-a}$	Thermal Resistance, Junction to Ambient	55	/W

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ELECTRICAL CHARACTERISTICS

 $T_C=25$ unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	BU406FI	$I_C= 200mA ; I_B= 0; L= 25mH$	200			V
		BU407FI		150			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage		$I_C= 5A; I_B= 0.5A$			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage		$I_C= 5A; I_B= 0.5A$			1.2	V
I_{CES}	Collector Cutoff Current		$V_{CE}= V_{CESmax}; V_{BE}= 0$			0.05 1.0	mA
I_{CES}	Collector Cutoff Current	BU406FI	$V_{CE}= 250V; V_{BE}= 0$ $V_{CE}= 350V; V_{BE}= 0; T_J=150$			0.1 1.0	mA
		BU407FI	$V_{CE}= 200V; V_{BE}= 0$ $V_{CE}= 200V; V_{BE}= 0; T_J=150$			0.1 1.0	
I_{EBO}	Emitter Cutoff Current		$V_{EB}= 5V; I_C= 0$			1.0	mA
f_T	Current-Gain—Bandwidth Product		$I_C= 0.5A ; V_{CE}= 10V$	4			MHz
t_{off}	Turn-Off Time		$I_C= 5A; I_{B1}= -I_{B2}= 0.5A$			0.75	μs